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Franck Moukanda Mbango, Ghislain Fraidy Bouesse, Fabien Ndagijimana. Material Relative Permittivity Determination From the Inhomogeneous Transmission-Line Secondary Parameters. IEEE Access, 2022, 10, pp.124595-124603. 10.1109/ACCESS.2022.3224464. hal-04051094

HAL Id: hal-04051094

https://hal.science/hal-04051094

Submitted on 19 Jan 2024

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Received 6 November 2022, accepted 18 November 2022, date of publication 24 November 2022, date of current version 1 December 2022.

Digital Object Identifier 10.1109/ACCESS.2022.3224464



Material Relative Permittivity Determination From the Inhomogeneous Transmission-Line Secondary Parameters

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ABSTRACT After further transmission line technique investigation, we propose a new approach to material characterization based on the combination of the propagation constant and the characteristic impedance of the transmission-line. Three main elements constitute the approach novelty's root: the determination of the propagation constant without using the eigenvalue principle, the improved mathematical expression of the characteristic impedance, and the automatically corrected coefficient. The two-line technique is based on three required measures, where the most extended fixture is partially filled with the specimen to be tested. As a result, the discontinuities caused by the geometric change of access interfaces and the waveguide dimensions have been solved. The characteristic impedance is determined straight and amended by a third polynomial function degree. The polynomial function and the amended correction coefficient determination are the facilitation parameters of the new approach technique. This new method allows the extraction of the material's complex relative permittivity. The procedure has been validated with the Rogers RO4003C, Alumina 99.6%, and Vinifera (based on the dielectric materials available in our laboratory) through the microstrip fixture in the scanned frequency (0.08–8) GHz by extracting its electric intrinsic parameters. The dielectric constants range from 1.1-10.4, where the thicknesses are 1.54 mm, 2.067 mm, and 1.078 mm have been used. Two identical microstrip test cells with the same geometric dimensions but various lengths have been manufactured. That promotes the feasibility of two measures simultaneously.

INDEX TERMS Characteristic impedance, discontinuity, material intrinsic parameters, propagation constant, semi-full transmission line.

I. INTRODUCTION

Electronic devices are increasingly attractive [1], [2], [3], [4] due to their potential application in several fundamental communication systems: solar cells [5], vehicle communications, satellites, new precision-guided munitions, etc. Understanding the electronic processes in these materials and devices is of fundamental importance to improve electronic performance and develop new materials for future technologies [6], [7]. That justifies the reason for developing advanced characterization techniques [8]. In addition, theoretical

The associate editor coordinating the review of this manuscript and approving it for publication was Wuliang Yin.

models are necessary regarding the properties of electronic materials. The literature suggests several alternative methods in the electromagnetic area [9], [10], [11], classified into two groups: broadband and narrowband [12], destructive and non-destructive [13], [14], [15], resonant and non-resonant [16], [17], direct and indirect methods, or distributed and lumped elements [11]. Inside these two groups are found six main techniques [18], [19], [20] according to the application domain and the state or kind of material to be characterized [21]. These six methods are Free-space [9], [22], [23], resonant cavity [24], [25], [26], capacitive or parallel plates capacitor [27], inductance [11], [28], probes [29], [30], and transmission line [31], [32], [33].

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Each method has its advantages and drawbacks (disadvantages) that may affect the accuracy of at least one parameter to be measured and the frequency domain to be covered. For example, all material shapes can't be used in the same test cell along with the six techniques. Also, while transmission line (also called waveguide) methods are suitable for broadband measurements, resonator cavity methods provide accurate results for low-loss materials. It means adapting the approach technique to extract parameters, the scanned frequency needed, the kind of material (shape, state, etc.), and the material application domain is essential.

The electronic materials are categorized into three, namely: electric, magnetic and magneto-electric materials. As mentioned above, we need to adapt the method according to the goals to reach. For high or thin wafer thicknesses, the transmission line is well-adapted. The transmission line technique is often used because they offer a good relationship between the accuracy, the scanned frequency, and the material to characterize. The transmission line can present one or two port accesses. The other end of the line can be open [34] or short-circuited [35] for one access. But the technique doesn't help extract the loss tangent.

Recently, a focus on the phase sensibility to extract the dielectric constant has attracted the researchers' attention by using the transmission coefficient through the low-pass filter design frame [36] but didn't cover a wider frequency band. In this paper, we present a technique using two rectangular coaxial identical transmission lines but different lengths $(l_2 \neq l_1)$ where the more extended is semi-filled. The developed method uses secondary transmission line parameters: the propagation constant [31], [37], and characteristic impedance combination. This challenge helps the material nature be known: electric, magnetic, or magneto-electric, and scanned a significant range frequency. The extended line is partially-filled up [38], [39], [40]. The two-line technique is famous and one of the best-known throughout the world. The two-line technique procedure utilizes the cascading wave T-matrix (CWM) principle. Such a technique focuses on the length difference via the propagation constant. From that, the new approach has been inspired, and determining the characteristic impedance is a new challenge. It is also proposed in this paper another way to extract the propagation constant instead of using the ideal line eigenvalues. The characteristic impedance mathematical expression has been presented with a particular improvement due to the corrected coefficient determination.

Furthermore, leading corrections at some steps of the method suggest a great view of solving the loss tangent. Finally, the two-line technique through the eigenvalues determination method has validated the new approach through result comparisons to achieve the technique extraction methodology. Therefore, three main points will be presented: the technique bases, experimental results validation, and analysis before a conclusion. The new approach is fundamentally based on the performance of the apparatus

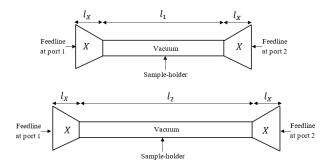


FIGURE 1. Two identical transmission lines with different lengths.

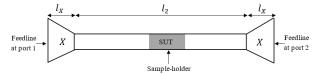


FIGURE 2. A transmission line l_2 partially filled with sample under test (SUT).

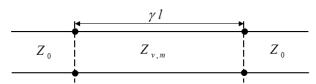


FIGURE 3. A transmission line \boldsymbol{I} in the presence of its secondary parameters.

(the sensor) that depends on the contact pressure applied to the sample under test.

II. MATHEMATICAL TECHNIQUE BASIS

Let us consider a two-port transmission line filled up with the vacuum, as illustrated in Fig. 1.

The T-matrixes for both test cells (whose lengths are l_1 and l_2) filled up with the vacuum are defined [32] as follows,

$$[T_1]_{\nu} = \frac{1}{S_{21}^{\nu_1}} \begin{bmatrix} S_{21}^{\nu_1} S_{12}^{\nu_1} - S_{11}^{\nu_1} S_{22}^{\nu_1} & S_{11}^{\nu_1} \\ -S_{22}^{\nu_1} & 1 \end{bmatrix}$$
(1)

$$[T_2]_{\nu} = \frac{1}{S_{21}^{\nu_2}} \begin{bmatrix} S_{21}^{\nu_2} S_{12}^{\nu_2} - S_{12}^{\nu_2} S_{22}^{\nu_2} & S_{11}^{\nu_2} \\ -S_{22}^{\nu_2} & 1 \end{bmatrix}$$
 (2)

and once the specimen to be characterized is partially filled in the extended test cell l_2 , as shown in Fig. 2, the transfer matrix becomes as given below,

$$[T_2]_m = \frac{1}{S_{21}^{m_2}} \begin{bmatrix} S_{21}^{m_2} S_{12}^{m_2} - S_{11}^{m_2} S_{22}^{m_2} & S_{11}^{m_2} \\ -S_{22}^{m_2} & 1 \end{bmatrix}$$
(3)

According to Figs. 1 and 2, which can be summarized as given in Fig. 3, the equations (1) - (3) can be re-written [41] as,

$$[T_1]_{\nu} = \frac{1}{2Z_{\nu}Z_0} \times \begin{bmatrix} 2Z_{\nu}Z_0 \cosh(\gamma_1 l_1) - A_1 & (Z_{\nu}^2 - Z_0^2) \sinh(\gamma_1 l_1) \\ - (Z_{\nu}^2 - Z_0^2) \sinh(\gamma_1 l_1) & 2Z_{\nu}Z_0 \cosh(\gamma_1 l_1) - A_1 \end{bmatrix}$$
(4)



For the extended transmission-line, the transfer T-matrix is rewritten as given below,

$$[T_2]_{\nu} = \frac{1}{2Z_{\nu}Z_0} \times \begin{bmatrix} 2Z_{\nu}Z_0 \cosh(\gamma_1 l_2) - A_2 & (Z_{\nu}^2 - Z_0^2) \sinh(\gamma_1 l_2) \\ - (Z_{\nu}^2 - Z_0^2) \sinh(\gamma_1 l_2) & 2Z_{\nu}Z_0 \cosh(\gamma_1 l_2) - A_2 \end{bmatrix}$$
(5)

and,

$$[T_2]_m = \frac{1}{2Z_m Z_0} \times \begin{bmatrix} 2Z_m Z_0 \cosh(\gamma_2 l_2) - A_3 & (Z_m^2 - Z_0^2) \sinh(\gamma_2 l_2) \\ - (Z_m^2 - Z_0^2) \sinh(\gamma_2 l_2) & 2Z_m Z_0 \cosh(\gamma_2 l_2) - A_3 \end{bmatrix}$$
(6)

where,

$$A_1 = \left(Z_v^2 + Z_0^2\right) \sinh\left(\gamma_1 l_1\right)$$

$$A_2 = \left(Z_v^2 + Z_0^2\right) \sinh\left(\gamma_1 l_2\right)$$

$$A_3 = \left(Z_m^2 + Z_0^2\right) \sinh\left(\gamma_2 l_2\right)$$

Both test cell lengths are linked, as shown in Fig. 2, and expressed in the following equation,

$$l_2 = l_1 + \Delta l \tag{7}$$

The supposed ideal transmission line is Δl long, and the vacuum propagation constant becomes as follows,

$$\gamma_{\nu}\Delta l = \gamma_1 \left(l_2 - l_1 \right) \tag{8}$$

Meanwhile, the propagation constant got in the presence of the material is,

$$\gamma_m \Delta l = \gamma_2 l_2 - \gamma_1 l_l \tag{9}$$

Several studies have been conducted using the two-line techniques [31], [42]. In that case, the resolution of the following equation,

$$[T_{12}]_{v} = [T_{2}]_{v} [T_{1}]_{v}^{-1}$$
 (10)

$$[T_{12}]_m = [T_2]_m [T_1]_v^{-1}$$
(11)

where,

$$[T_{12}]_{\nu,m} = \begin{bmatrix} T_{11_{\nu,m}}^{(1)} & T_{12_{\nu,m}}^{(2)} \\ T_{21_{\nu,m}}^{(3)} & T_{22_{\nu,m}}^{(4)} \end{bmatrix}$$
(12)

establishes a mathematical relation between the transmission line characteristic impedance (Z_v, Z_m) and the impedance access Z_0 . The development and calculation give,

$$T_{12_{\nu,m}}^{(2)} T_{21_{\nu,m}}^{(3)} = \frac{\left(Z_0^2 - Z_{\nu,m}^2\right)}{8Z_{\nu,m}^2 Z_0^2} \left\{1 - \cosh\left(2\gamma_{\nu,m}\Delta l\right)\right\} \tag{13}$$

The equations (1)-(3) and (10)-(11) through (12) allow the analytical relation between the measured scattering parameters and the material properties to be proposed to solve the problem.

Let us consider that $P_{v,m} = T_{12_{v,m}}^{(2)} \cdot T_{21_{v,m}}^{(3)}$ and $Y_{v,m} = \cosh(2\gamma_{v,m}\Delta l)$. The resolution of (13) gives four possibilities for results. It's found out that, (14), as shown at the bottom of the page. Or, (15), as shown at the bottom of the page. Simultaneously, the new mathematical formulation through (4)-(6) allows determining the propagation constant as given in (16),

$$\gamma_{\nu,m} \Delta l = \cosh^{-1} \left(\frac{T_{11_{\nu,m}}^{(1)} + T_{22_{\nu,m}}^{(4)}}{2} \right)$$
(16)

The literature defines the propagation constant through the Maxwell equation as a combination of the attenuation coefficient αl and the electric length $\beta l = \theta$. In that case,

$$\gamma \Delta l = \alpha l + \underbrace{\beta \Delta l}_{\theta} \tag{17}$$

During the procedure, the electric length must be linearized as the phase velocity doesn't depend on the frequency when the transverse electromagnetic (TEM) mode propagates.

An automatic coefficient is determined to correct the characteristic impedance of the fixture when the material under test is inserted. By considering X the correction coefficient, given as shown (18) below,

$$X = \frac{\sum_{1}^{n} \theta_m}{\sum_{1}^{n} \theta_v} - \frac{\sum_{1}^{n} \theta_v}{\sum_{1}^{n} \theta_m}$$
 (18)

both characteristic impedances are (19), as shown at the bottom of the next page, and (20), as shown at the bottom of the next page. The equations (16), (18), (19) and (20) represent the considerable contribution and novelty developed in this paper.

The complex effective permittivity is given in the following equation,

$$\varepsilon_{eff}^* = \frac{\gamma_d}{\gamma_v^c} \frac{Z_v^*}{Z_m^*} \tag{21}$$

$$Z_{\nu,m} = \pm Z_0 \sqrt{\frac{1}{P_{\nu,m} - 1}} + \left\{ Y_{\nu,m} + 2\sqrt{2}\sqrt{2P_{\nu,m}^2 + (1 - Y_{\nu,m})P_{\nu,m}} - (1 + 4P_{\nu,m}) \right\}$$
(14)

$$Z_{\nu,m} = \pm Z_0 \sqrt{\frac{1}{1 - P_{\nu,m}}} + \left\{ -Y_{\nu,m} + 2\sqrt{2}\sqrt{2P_{\nu,m}^2 + (1 - Y_{\nu,m})P_{\nu,m}} + (1 + 4P_{\nu,m}) \right\}$$
(15)

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where

$$\gamma_d^* = (\alpha_m - \alpha_v) \, \Delta l + j\theta_m \tag{22}$$

$$\gamma_{v}^{c} = j\theta_{v} \tag{23}$$

$$Z_m^* = Z_m' + jZ_m'' (24)$$

and

$$Z_{v}^{*} = Z_{v}' + jZ_{v}'' \tag{25}$$

When developing (21), it is observed that the real part of that expression has an uncertainty coefficient $\Delta \varepsilon'_{eff}$, changing with the frequency.

$$\Delta \varepsilon'_{eff} = \left\{ \frac{\theta_m Z''_v Z''_m + \alpha_d \left(Z'_m Z''_v - Z''_m Z'_v \right) \Delta l}{\theta_v \left(Z'_m \right)^2} \right\}$$
(26)

In that case, the real part of effective permittivity is about,

$$\varepsilon_{eff}' = \frac{\theta_m}{\theta_v} \frac{Z_a'}{Z_m'} \tag{27}$$

The imaginary part of the equation (21) is below,

$$\varepsilon_{eff}^{"} = \frac{Z_m^{"} Z_v^{"} \theta_m - \alpha_m \left(Z_m^{"} Z_v^{'} + Z_m^{"} Z_v^{"} \right) \Delta l - Z_m^{"} Z_v^{'} \theta_m}{\theta_v \left(Z_m^{'} \right)^2}$$
(28)

This expression highlights two parts: the loss coefficient, as given in (29),

$$\varepsilon_{eff_c}^{"} = -\frac{\alpha_d \left(Z_m^{\prime} Z_v^{\prime} + Z_m^{"} Z_v^{"} \right) \Delta l}{\theta_v \left(Z_m^{\prime} \right)^2} \tag{29}$$

and the uncertainty term, as shown

$$\Delta \varepsilon_{eff}^{"} = \frac{\left(Z_{\nu}^{"} Z_{m}^{'} - Z_{m}^{"} Z_{\nu}^{'}\right) \theta_{m}}{\theta_{\nu} \left(Z_{m}^{\prime}\right)^{2}} \tag{30}$$

with the dielectric attenuation coefficient as follows,

$$\alpha_d = \alpha_m - \alpha_v \tag{31}$$

The effective loss tangent is determined from (27) and (29), as given below,

$$\tan \delta_{eff} = \frac{\alpha_d}{\beta_m} \left(1 + \frac{Z_m'' Z_\nu''}{Z_\nu' Z_m''} \right) \tag{32}$$

The equation (32) can also be rewritten as follows,

$$\tan \delta_{eff} = \frac{1}{\beta_{\nu}} \left(\frac{\alpha_m}{\sqrt{\varepsilon'_{eff}}} - \alpha_{\nu} \right) \left(1 + \frac{Z''_m Z''_{\nu}}{Z'_{\nu} Z'_m} \right). \tag{33}$$

III. DIELECTRIC MATERIAL EXTRACTION

Here is described a new method of material characterization when using the inhomogenous fixture, especially the microstrip test cell. From the cell design, as shown in Fig. 4 below,

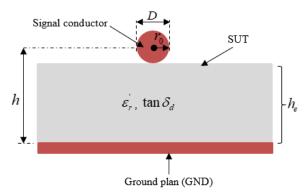


FIGURE 4. A simplified design of the microstrip line having a circular signal conductor.



FIGURE 5. Test cell design is not connected to the VNA without the SUT.

The material thickness is symbolized by h_e while the considered is defined as,

$$h = h_e + \frac{D}{2} \tag{34}$$

The signal conductor is circular with a diameter $D=2r_0$, where r_0 is its radius. The transition from the effective complex permittivity ε_{eff}^* to the relative complex permittivity ε_r^*

$$Z_{\nu} = Z_0 \sqrt{\frac{1}{1 - P_{\nu}}} + \left\{ -Y_{\nu} + 2\sqrt{2}\sqrt{2P_{\nu}^2 + (1 - Y_{\nu})P_{\nu}} + (1 + 4P_{\nu}) \right\}$$
 (19)

$$Z_m = \frac{Z_0}{X} \sqrt{\frac{1}{P_m - 1}} + \left\{ Y_m + 2\sqrt{2}\sqrt{2P_m^2 + (1 - Y_m)P_m} - (1 + 4P_m) \right\}$$
 (20)







FIGURE 6. (a) The SUT inside of the microstrip transmission line trapper. (b) Top view of the SUT inside of trapper.

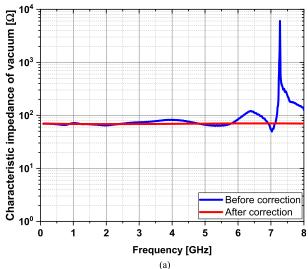
can be done by using the following (35),

$$\varepsilon_r^* = 4 \frac{h_e}{D} \frac{1}{\exp\left\{\frac{\ln\left(\frac{1}{4} + 4\frac{h_e}{D}\right)}{\varepsilon_{eff_R}^*}\right\} - x}$$
(35)

where $x \approx 0.86$. From all corrections made beforehand through (26) and (30), it's defined a new effective complex permittivity substituted to (27) and (33), and becomes as given below,

$$\varepsilon_{eff_R}^* = \varepsilon_{eff}' \left(1 - j \tan \delta_{eff} \right) \tag{36}$$

The method focuses on wafers from the designed fixture. This new material characterization procedure answers industrial inquiries or needs and researchers by reducing the time and money spent, improving accuracy, and expanding the scanned frequency.



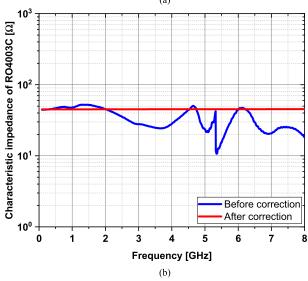


FIGURE 7. (a) Vacuum characteristic impedance using a circular signal conductor of a microstrip fixture. (b) The characteristic impedance of RO4003C is inserted in a circular signal conductor microstrip fixture.

IV. MEASUREMENT SET-UP AND TECHNIQUE VALIDATION

Two microstrip test cells have been designed and manufactured. Both fixtures are identical, with $l_1=50\,\mathrm{mm}$ and $l_2=70\,\mathrm{mm}$ lengths. The signal conductor is circular with an outer radius $r_0=$ of 2.5 mm, and the test cell is suitable for changing material thickness. The brass has been used as the ground plan and the signal conductors. Rogers RO4003C, alumina 99.6%, and vinifera have been used to validate the developed process and have a thickness (h) of 1.54 mm, 2.067 mm, and 1.078 mm. To validate the method, the vector network analyzer (VNA) Anritsu MS4642B was utilized as the radiofrequency (RF) measuring analyzer (VNA). In addition, we have investigated the frequency range (0.08–8) GHz. Therefore, three measurements are required: two in the presence of a vacuum, using both test cells, and one with the most extended fixture, which traps the SUT. The measurement

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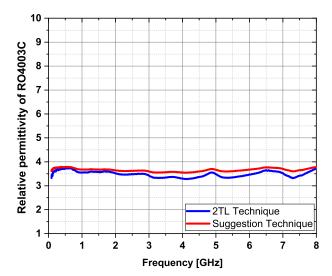


FIGURE 8. The extracted relative permittivity of RO4003C with both techniques.

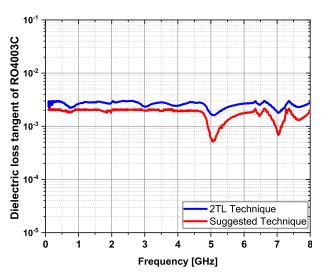


FIGURE 9. The extracted dielectric loss tangent of RO4003C.

fixture is depicted in Figs. 5 and 6. It has been fabricated to experiment with samples and validate the suggested method.

When the SUT is trapped inside the fixture, Fig. 5, becomes as illustrated in Fig. 6.

The measurement apparatus was designed and adapted for hard, soft, and flexible wafers. Liquid, mud, and powder materials might be used with another fixture. The knob controls the material thickness. The 2.067 mm, 1.54 mm, and 1.078 mm are thicknesses of alumina 99.6%, RO4003C, and vinifera, respectively. All samples are 20 mm long and rectangular to fit the apparatus designed to measure simultaneously the sample under test, placed on the extended line and the vacuum case for the shortest line. The microwave test cell holds samples up to 10 mm thick.

The material trapper is designed to ease the measurements and can be made both at the same time.

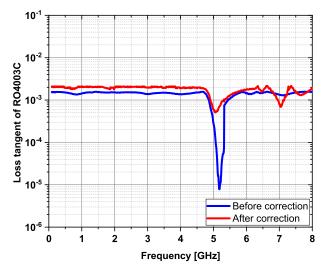


FIGURE 10. Comparison of loss tangent of RO4003C with the new approach.

V. EXPERIMENTAL RESULTS AND DISCUSSION

Below are the results of the characteristic impedances, the relative permittivity, and the loss tangent of the sample material under test.

It observes that the extracted parameters, whose curves are plotted in Fig. 7, don't allow variations to appear brought on by the resonance frequencies. Also, the polynomial function has been to smooth curves, as mentioned in reference [29].

Fig. 8 is derived from the result (35). The new approach's complex effective permittivities are calculated using (36). The correction coefficient is $X \approx 0.846$ when utilizing (18). Its formulation says that it depends on the fixture and the sample material.

At the same time, (32) and (33) are used to determine the effective loss tangent. From the comparison of both expressions, it is well noticed that,

$$\left(1 + \frac{Z_m'' Z_\nu''}{Z_\nu' Z_m'}\right) \ll 2$$
(37)

When the dielectric under test is very low-loss. In that case, both extracted loss tangents will differ, as seen in Fig. 9.

Fig. 10 shows the impact of the correction of the effective complex permittivity when using (33).

The method is always compared to the two-line technique, as depicted in Figs. 8-12., which is the most commonly used method. But we set up some particular mechanic processes to reduce their impacts. Hence, the device under test dimensions are well-controlled, especially during the cutting stage. Furthermore, the contact force is a significant parameter to ensure good electrical contact with the sample. This provides reliable measurements for a good study. Under these conditions, the method provides an error of less than 5% on the relative permittivity into the entire frequency range. The following table compares the manufacturer sample intrinsic parameter values and those the new approach got.

As summarized in table 1, the new SUT characterization approach is well-adapted. For example, the median relative



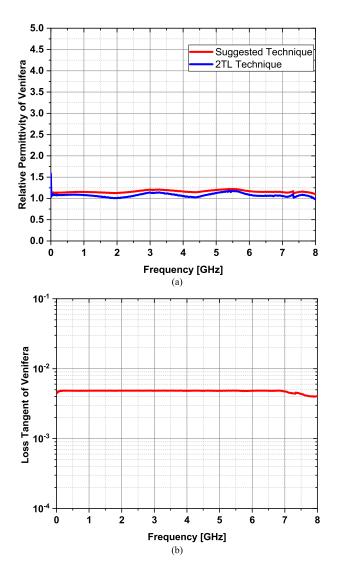


FIGURE 11. (a) The extracted dielectric constant parameter of Vinifera. (b) The extracted dissipation factor parameter of Vinifera.

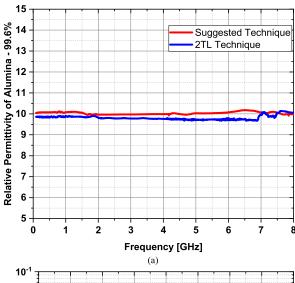
TABLE 1. Comparison extracted results comparison at 2 GHz.

2.5	0.0001
Manufacturer 3.55	0.0021
2TL technique 3.519	0.00282
New approach 3.642	0.00194

permittivity values are 3.657 and 3.482 for the suggested method and the two-line technique (using the eigenvalue principle), respectively. In addition, flexible (vinifera) and rigid (alumina 99.6%) wafers have been tested with the same measuring apparatus.

Figs. 11 and 12 are the vinifera and alumina dielectric constant (DK) and dissipation factor (DF) parameters graphs and confirm the suggested method's excellent approach.

Table 2 shows an excellent agreement with those given by the manufacturer; even the method they used hasn't been provided to evaluate the error made.



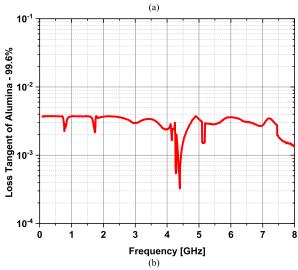


FIGURE 12. (a) The alumina 99.6% extracted dielectric constant parameter. (b) The alumina 99.6% extracted dissipation factor parameter.

TABLE 2. Comparison of the average extracted DK in the frequency range 0.08-8 GHz.

3-11.5	2.55	
J 11.J	3.55	none
813	3.482	1.079
0.031	3.657	1.163

TABLE 3. Comparison of the average extracted DF in the frequency range 0.08-8 GHz.

Designation	Alumina 99.6%	RO4003C	Vinifera
Manufacturer	none	0.0021-	none
		0.0027	
Two-line tech.	0.00351	0.00259	0.00383
Suggested	0.00304	0.00167	0.00476
Approach			

After using the microstrip measuring test cell depicted in Figs. 5 and 6, and summarizing the DF, illustrated in Figs. 10, 11b, and 12b alongside table 3, the technique has

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shown his ability to test material with a minimum DF of 10^{-3} and samples with large and/or small thicknesses in a wide band.

VI. CONCLUSION

We have developed a new approach that combines the propagation constant (without using the eigenvalue principle) and the characteristic impedance to extract the electric intrinsic material properties. In addition, we have investigated how to correct that formula and improved the technique through an automatic coefficient determination. Moreover, we have scanned a large frequency band to validate the principle using three sample materials and compared the results with those proposed by the manufacturer on one side and the two transmission-line (2TL) techniques on the other. This method has the advantage of characterizing simultaneously electric, magnetic, and magneto-electric materials. Moreover, the discontinuity impacts are better solved through this technique.

Furthermore, with fewer measurements (three needed), the semi-filled fixture was enough to experiment with the Rogers RO4003C, alumina 99.6%, and vinifera as available various dielectric materials in our lab., in the frequency range (0.08–8) GHz with error evaluation of less than 5% on the relative permittivity. Finally, the new approach successfully reached the study using the same inhomogeneous frame, and those results were obtained from the two-line technique using the eigenvalue extraction principle. Results from the new approach taught that the order modes, which typically hindered several different technique procedures above a particular frequency, are not a limitation in this new technique. The measuring device is suitable for wafer insulators, and the knob has been set up to control the dielectric under test thickness. One of the advantages of developing this approach is to use magnetic, electric, and magneto-electric materials with the same fixture. There is no need to provide necessarily the material nature and state in advance.

ACKNOWLEDGMENT

The authors sincerely thank the anonymous reviewers for their attentive revision and suggestions to improve the article's quality.

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